

V_{DSS}	30V
$R_{DS(on)(Max.)}$	3.2mΩ
I_D	±40A
P_D	30W

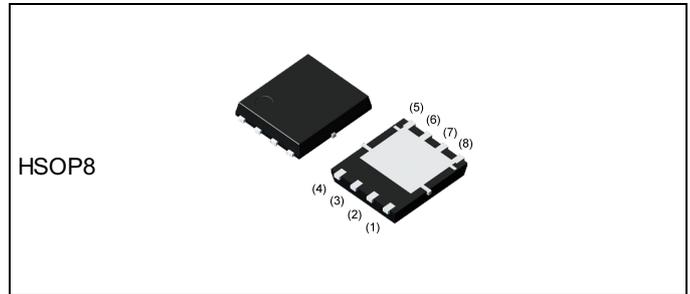
●Features

- 1) Low on - resistance.
- 2) High Power small mold Package (HSOP8).
- 3) Pb-free lead plating ; RoHS compliant.
- 4) Halogen Free.

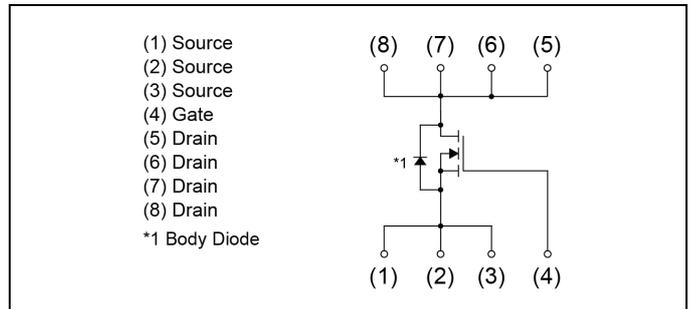
●Application

Switching

●Outline



●Inner circuit



●Packaging specifications

Type	Packing	Embossed Tape
	Reel size (mm)	330
Tape width (mm)	12	
Basic ordering unit (pcs)	2500	
Taping code	TB	
Marking	RS1E240BN	

●Absolute maximum ratings ($T_a = 25^\circ\text{C}$, unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage	V_{DSS}	30	V	
Continuous drain current	$T_c = 25^\circ\text{C}$	I_D^{*1}	±40	A
	$T_a = 25^\circ\text{C}$	I_D	±24	A
Pulsed drain current	I_{DP}^{*2}	±96	A	
Gate - Source voltage	V_{GSS}	±20	V	
Avalanche current, single pulse	I_{AS}^{*3}	40	A	
Avalanche energy, single pulse	E_{AS}^{*3}	140	mJ	
Power dissipation	P_D^{*1}	30	W	
	P_D^{*4}	3	W	
Junction temperature	T_j	150	°C	
Operating junction and storage temperature range	T_{stg}	-55 to +150	°C	

● Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - case	R_{thJC}^{*1}	-	-	4.2	°C/W
Thermal resistance, junction - ambient	R_{thJA}^{*4}	-	-	41.7	°C/W

● Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 1mA$	30	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$	$I_D = 1mA$ referenced to 25°C	-	21	-	mV/°C
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 30V, V_{GS} = 0V$	-	-	1	μA
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 16V, V_{DS} = 0V$	-	-	± 100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10, I_D = 1mA$	1.0	-	2.5	V
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_j}$	$I_D = 1mA$ referenced to 25°C	-	-3	-	mV/°C
Static drain - source on - state resistance	$R_{DS(on)}^{*4}$	$V_{GS} = 10V, I_D = 24A$	-	2.3	3.2	m Ω
		$V_{GS} = 4.5V, I_D = 24A$	-	3.3	4.6	
Gate resistance	R_G	f=1MHz, open drain	-	1.2	-	Ω
Forward Transfer Admittance	$ Y_{fs} ^{*4}$	$V_{DS} = 5V, I_D = 24A$	18	-	-	S

*1 $T_c=25^\circ\text{C}$, Limited only by maximum temperature allowed.

*2 $P_w \leq 10\mu\text{s}$, Duty cycle $\leq 1\%$

*3 $L \approx 0.05\text{mH}$, $V_{DD} = 24V$, $R_G = 25\Omega$, STARTING $T_j = 25^\circ\text{C}$ Fig.3-1,3-2

*4 Mounted on a Cu Board (40×40×0.8mm)

*5 Pulsed

● Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	C_{iss}	$V_{GS} = 0V$	-	3900	-	pF
Output capacitance	C_{oss}	$V_{DS} = 15V$	-	450	-	
Reverse transfer capacitance	C_{rss}	$f = 1\text{MHz}$	-	350	-	
Turn - on delay time	$t_{d(on)}^{*4}$	$V_{DD} \approx 15V, V_{GS} = 10V$	-	25	-	ns
Rise time	t_r^{*4}	$I_D = 12A$	-	70	-	
Turn - off delay time	$t_{d(off)}^{*4}$	$R_L \approx 1.25\Omega$	-	115	-	
Fall time	t_f^{*4}	$R_G = 10\Omega$	-	26	-	

● Gate charge characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions		Values			Unit
				Min.	Typ.	Max.	
Total gate charge	Q_g^{*4}	$V_{DD} \approx 15V$ $I_D = 24A$	$V_{GS} = 10V$	-	70	-	nC
Gate - Source charge	Q_{gs}^{*4}		$V_{GS} = 4.5V$	-	35	-	
Gate - Drain charge	Q_{gd}^{*4}			-	14	-	

● Body diode electrical characteristics (Source-Drain) ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Continuous forward current	I_S	$T_a = 25^\circ\text{C}$	-	-	2.5	A
Pulse forward current	I_{SP}^{*2}		-	-	96	A
Forward voltage	V_{SD}^{*4}	$V_{GS} = 0V, I_S = 2.5A$	-	-	1.2	V

● Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

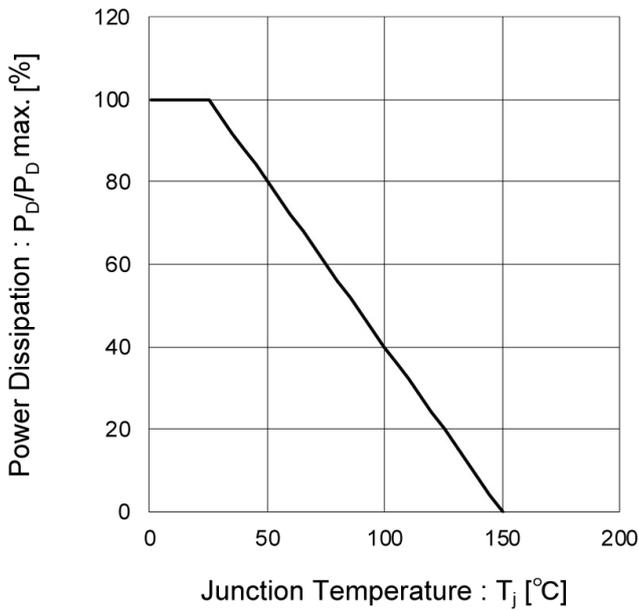


Fig.2 Maximum Safe Operating Area

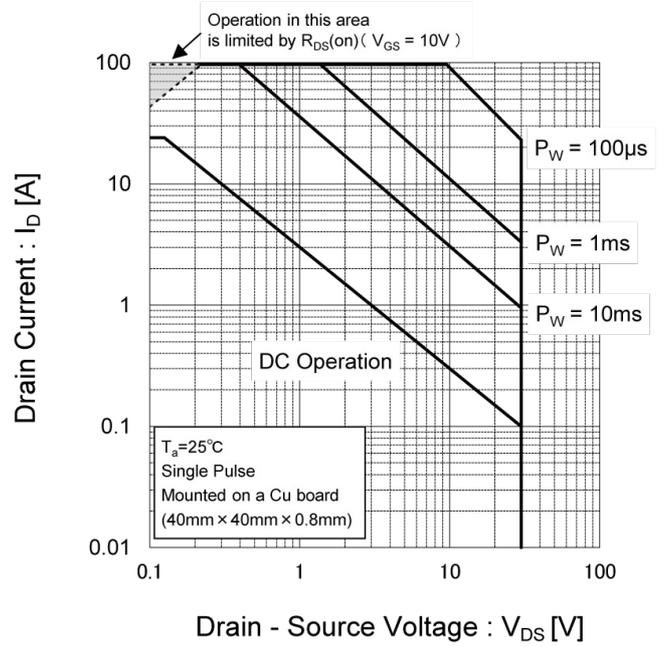


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

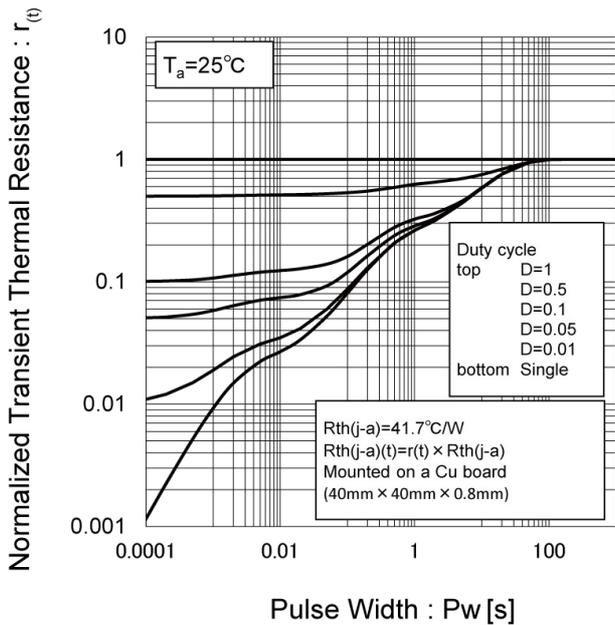
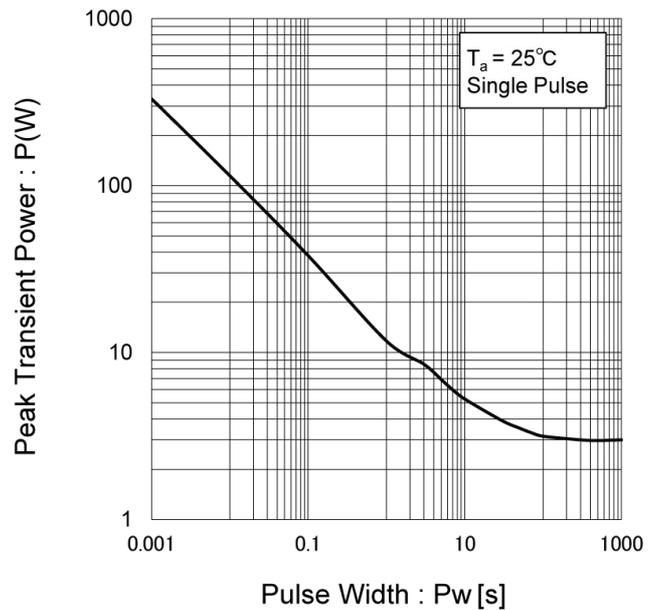


Fig.4 Single Pulse Maximum Power dissipation



●Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

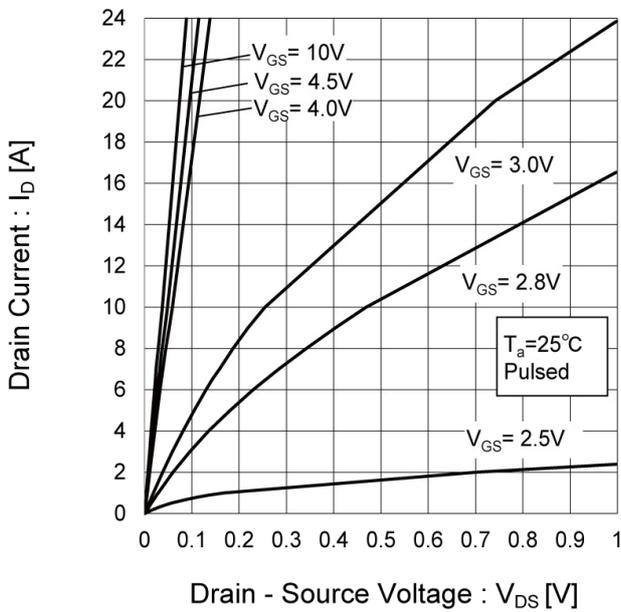


Fig.6 Typical Output Characteristics(II)

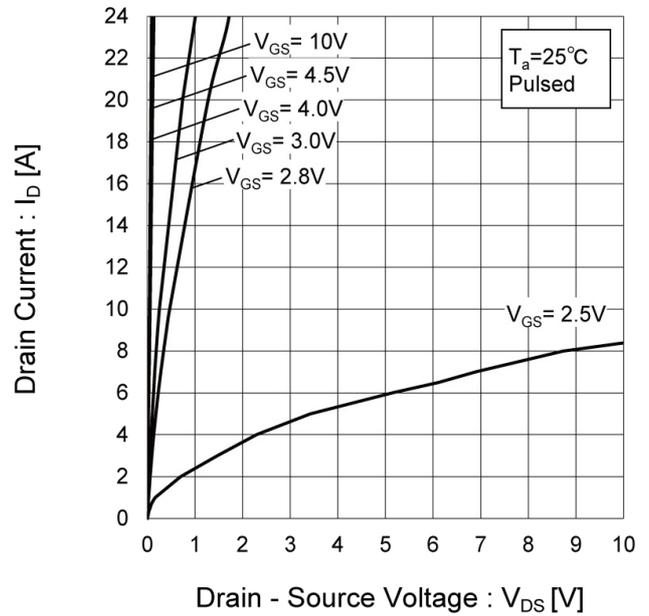


Fig.7 Breakdown Voltage vs. Junction Temperature

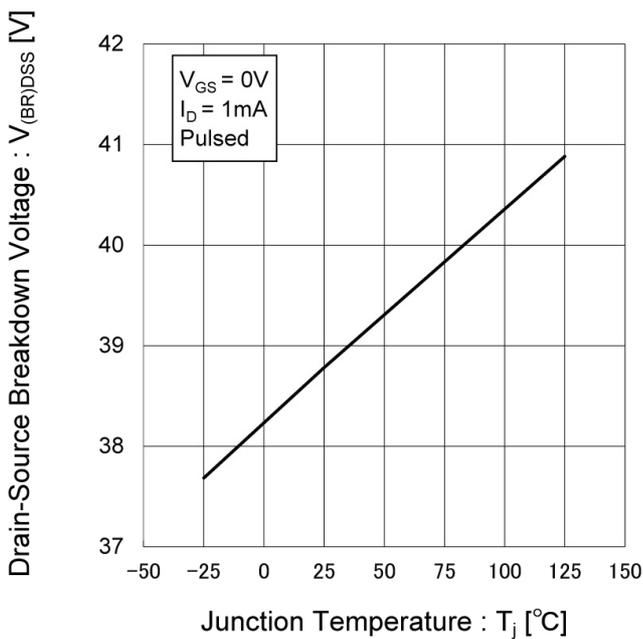
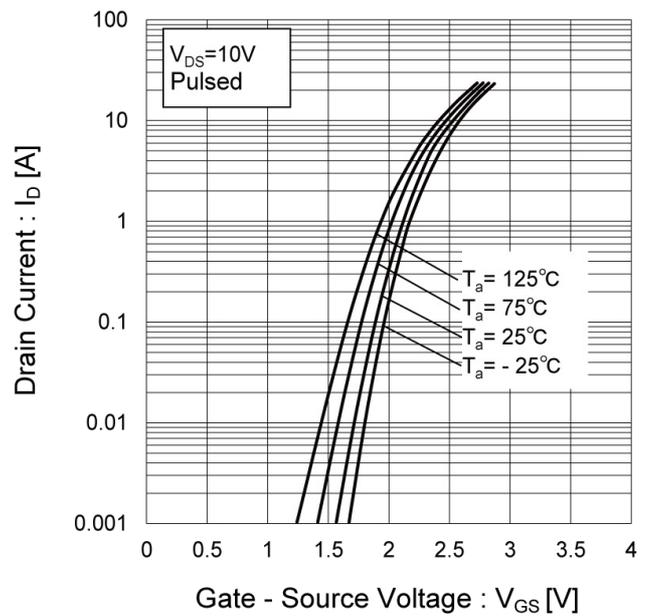


Fig.8 Typical Transfer Characteristics



●Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs. Junction Temperature

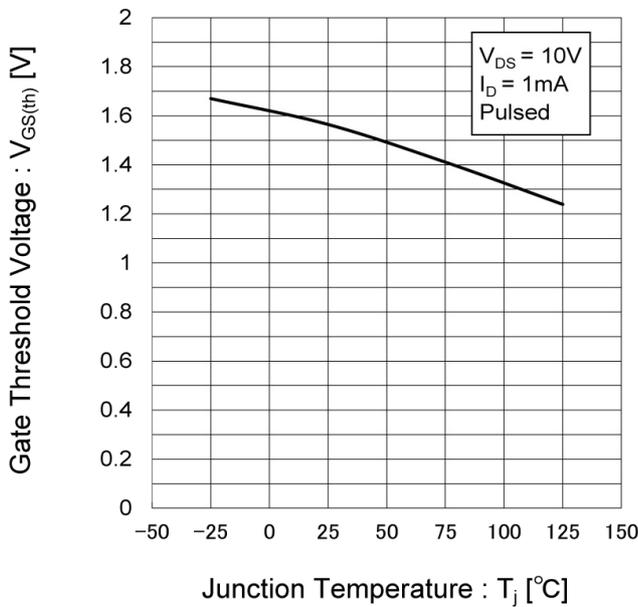


Fig.10 Forward Transfer Admittance vs. Drain Current

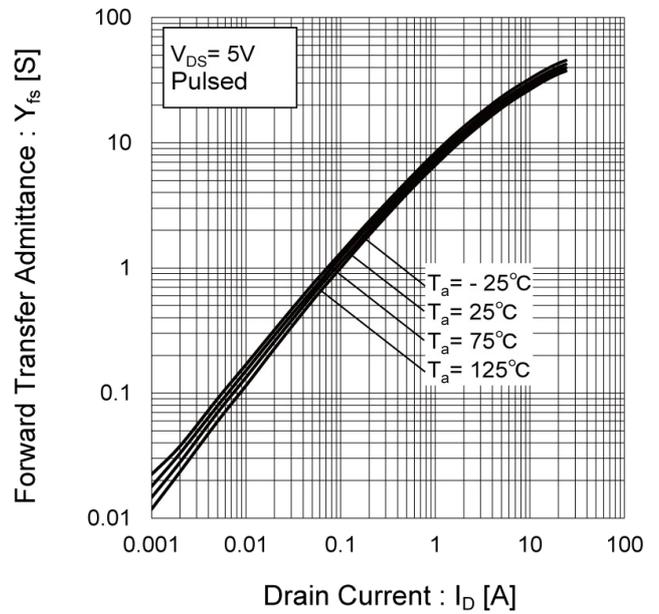


Fig.11 Drain Current Derating Curve

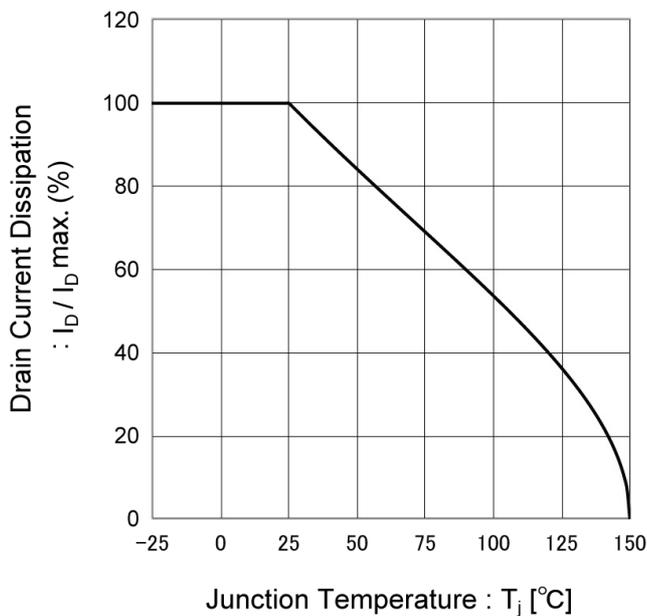
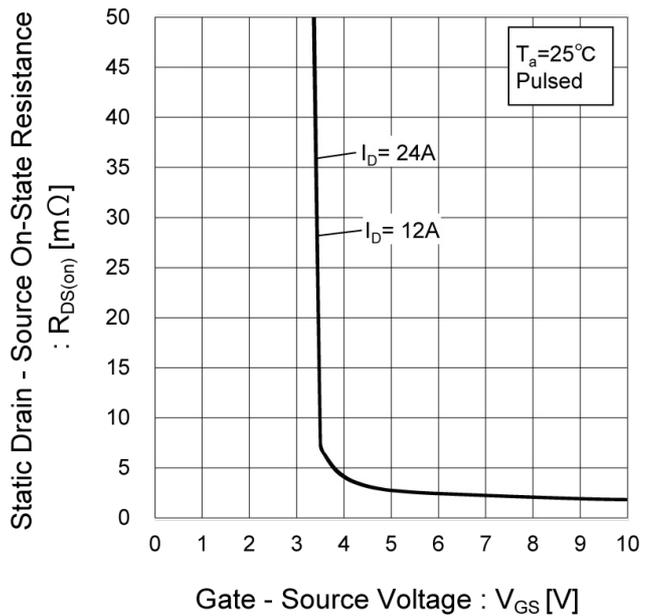


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



● Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

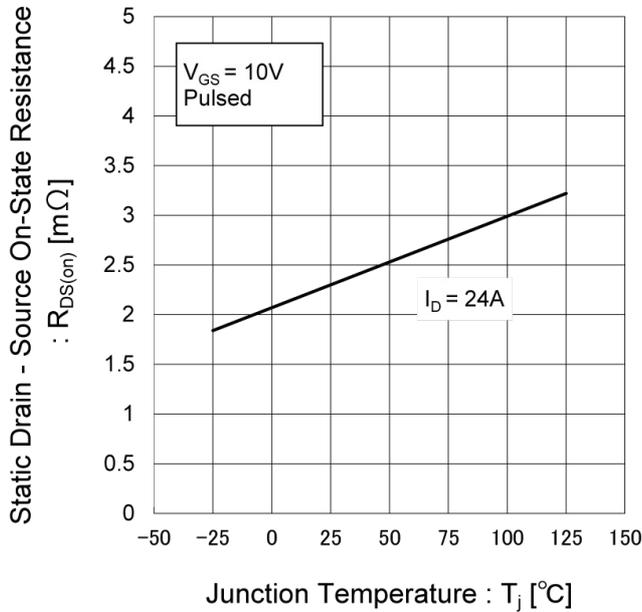


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)

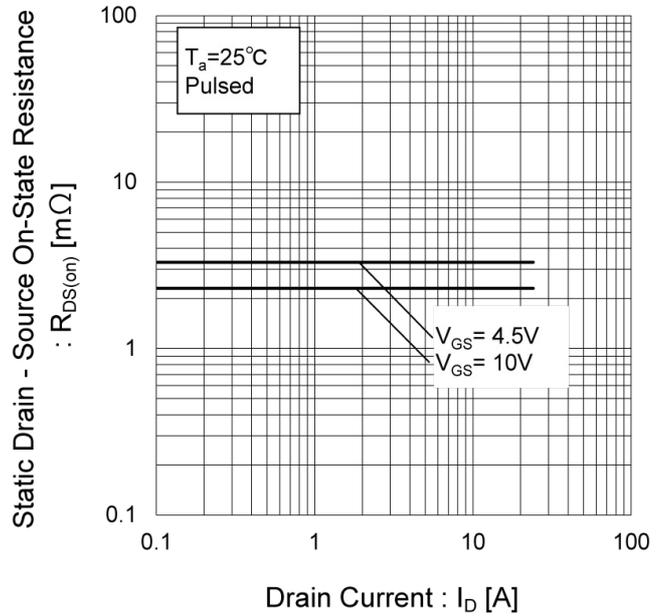


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

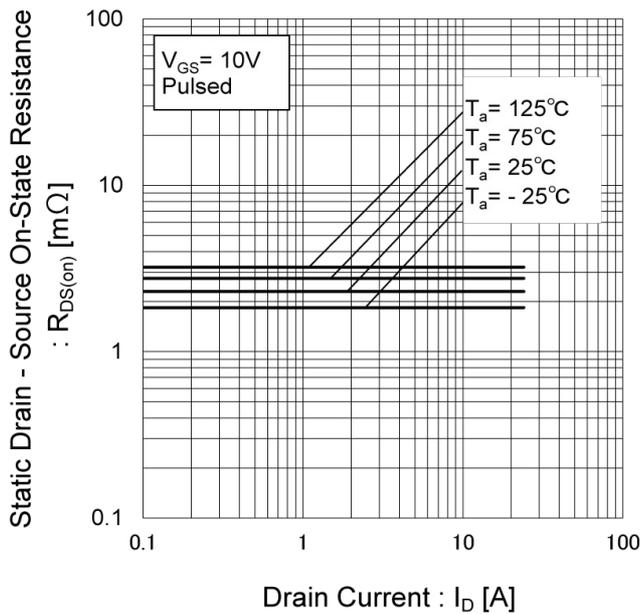
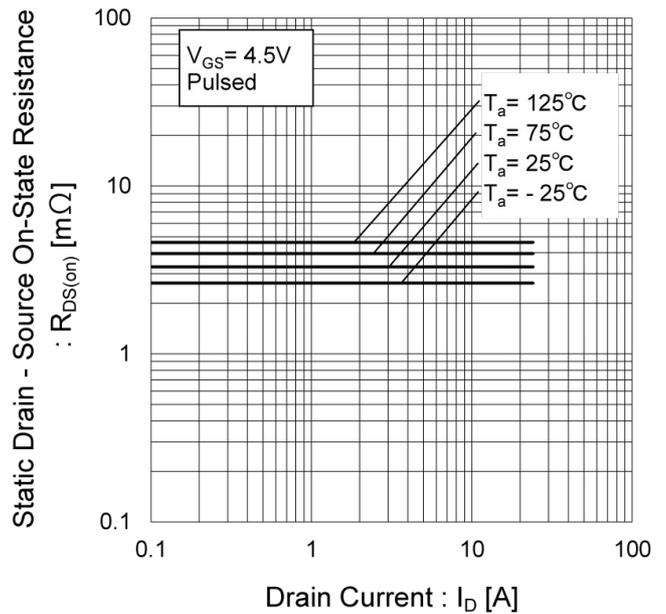


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)



●Electrical characteristic curves

Fig.17 Typical Capacitance vs. Drain - Source Voltage

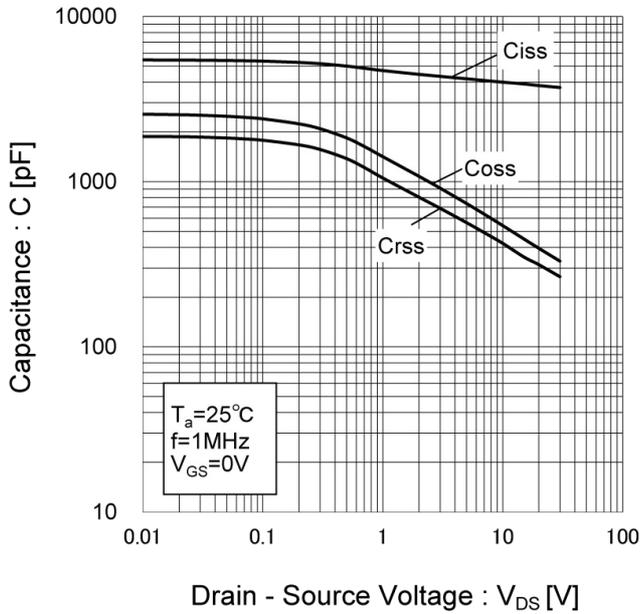


Fig.18 Switching Characteristics

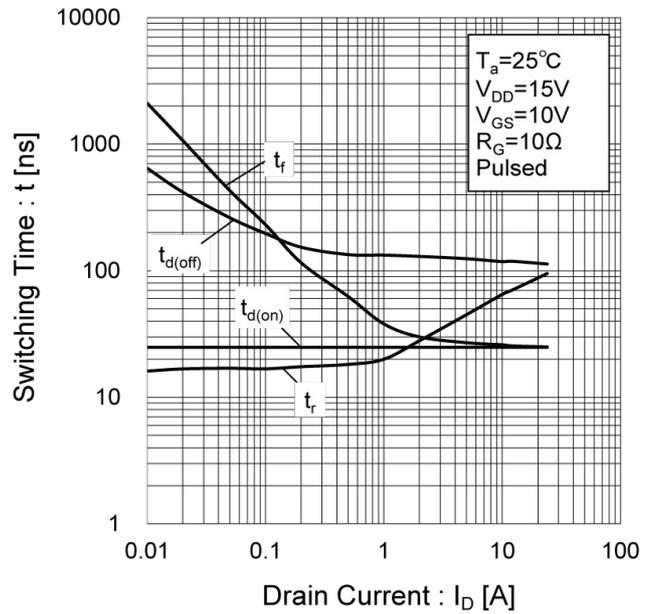


Fig.19 Dynamic Input Characteristics

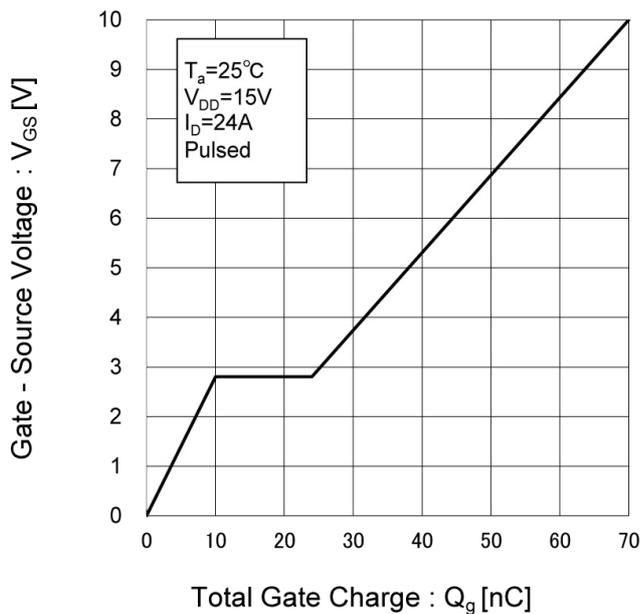
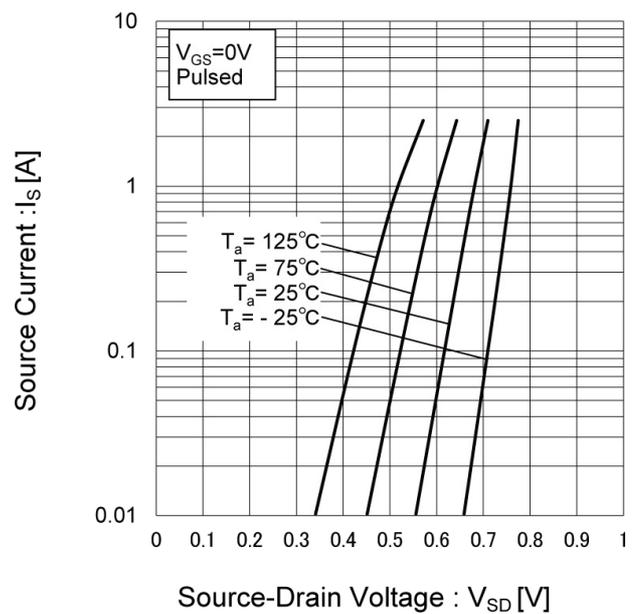


Fig.20 Source Current vs. Source Drain Voltage



● Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

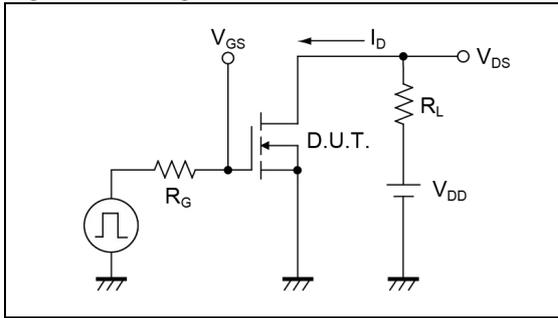


Fig.1-2 Switching Waveforms

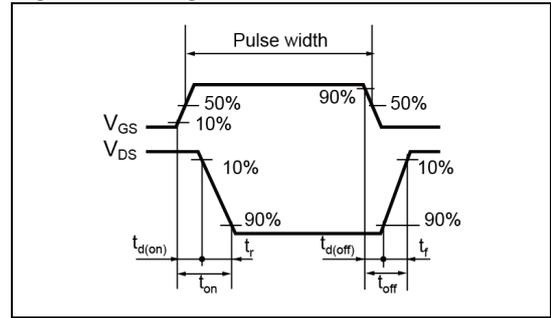


Fig.2-1 Gate Charge Measurement Circuit

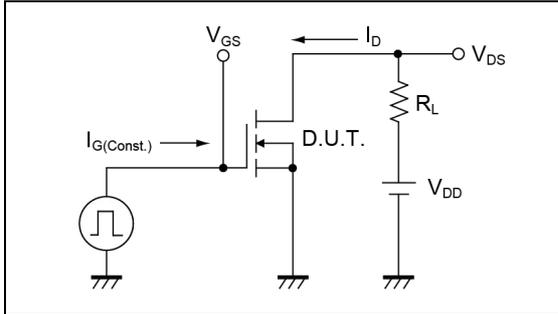


Fig.2-2 Gate Charge Waveform

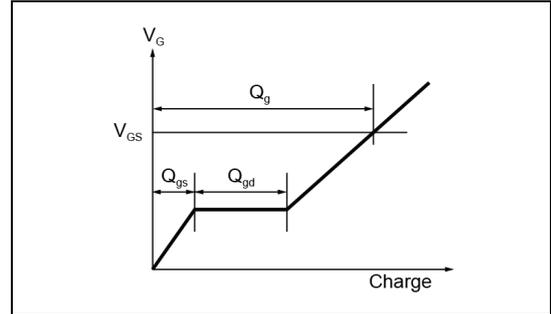


Fig.3-1 Avalanche Measurement Circuit

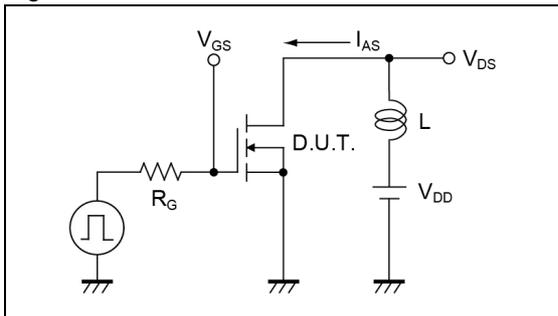
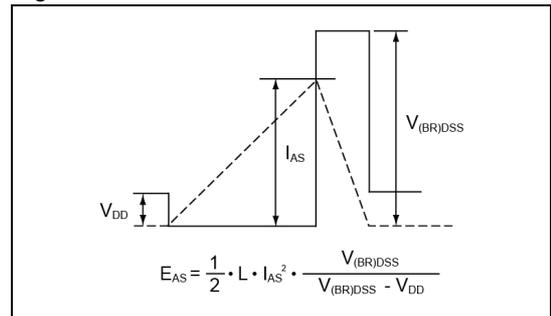


Fig.3-2 Avalanche Waveform

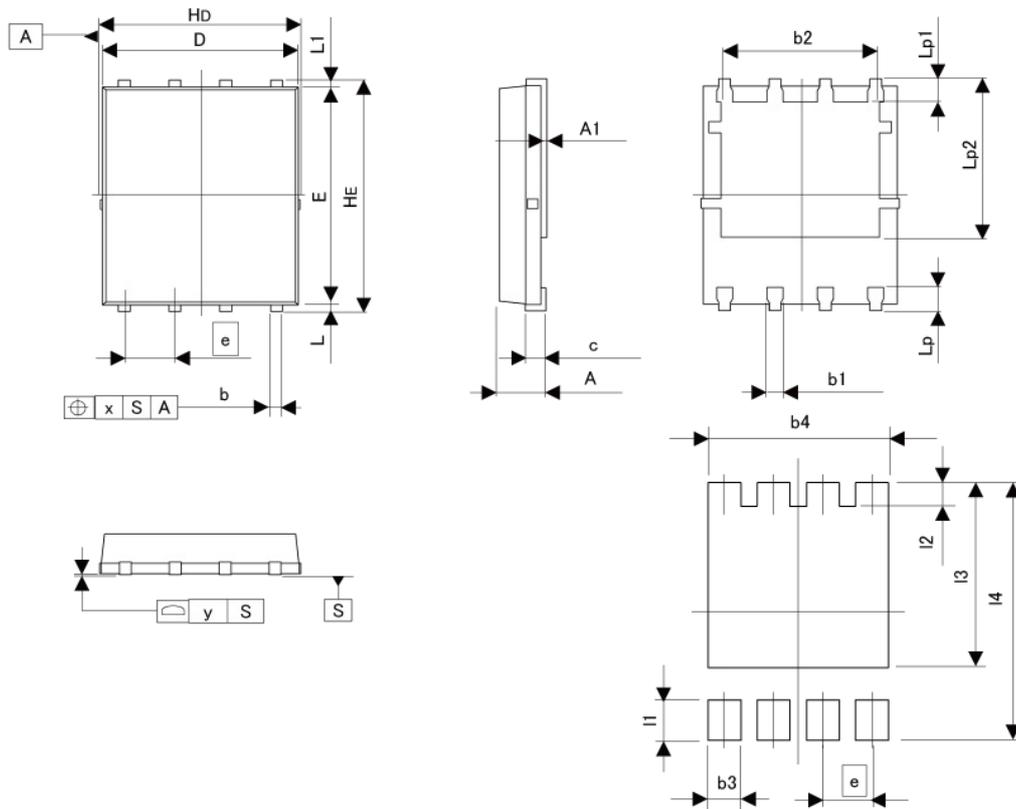


● Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

●Dimensions

HSOP8 (5 x 6)



Pattern of terminal position areas
[Not a pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.90	1.10	0.035	0.043
A1	0.00	0.05	0.000	0.002
b	0.24	0.42	0.009	0.017
b1	0.29	0.49	0.011	0.019
b2	3.81	4.21	0.150	0.166
c	0.20	0.30	0.008	0.012
D	4.80	5.00	0.189	0.197
E	5.60	5.80	0.220	0.228
e	1.27		0.050	
Hd	4.90	5.10	0.193	0.201
HE	5.90	6.10	0.232	0.240
L	0.07	0.25	0.003	0.010
L1	0.07	0.25	0.003	0.010
Lp	0.50	0.70	0.020	0.028
Lp1	0.52	0.72	0.020	0.028
Lp2	3.92	4.32	0.154	0.170
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b3	-	0.59	-	0.023
b4	-	4.21	-	0.166
I1	-	0.80	-	0.031
I2	-	0.82	-	0.032
I3	-	4.32	-	0.170
I4	-	6.10	-	0.240

Dimension in mm/inches

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